



TITLE: A SILICIDED BURIED BITLINE PROCESS FOR A NON-VOLATILE MEMORY CELL

INVENTOR(S): Daniel Sobek, Timothy J. Thurgate, Mark W. Randolph

USSN: 09/885,426 Attorney Docket # AMD-E306

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Replacement Sheet

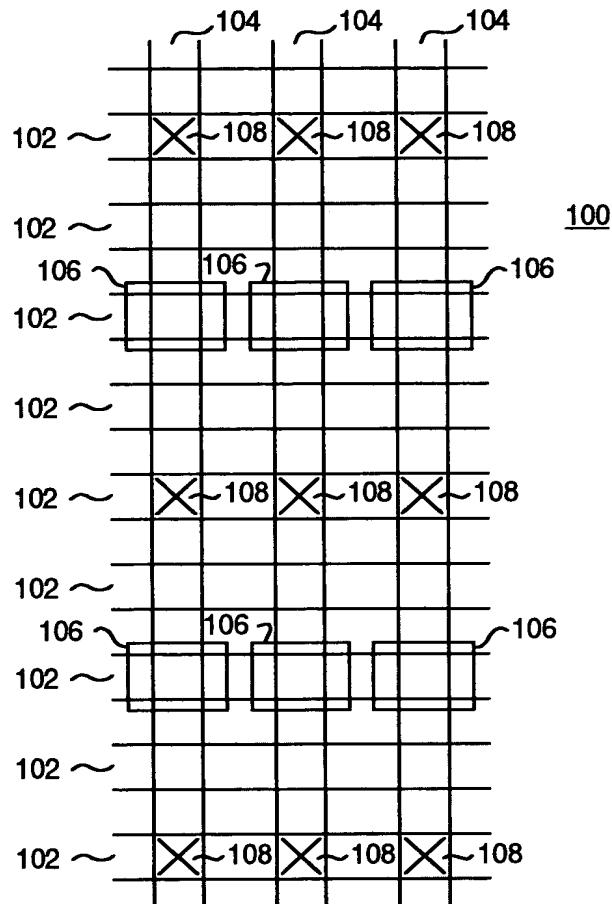


FIG. 1

PRIOR ART

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Replacement Sheet

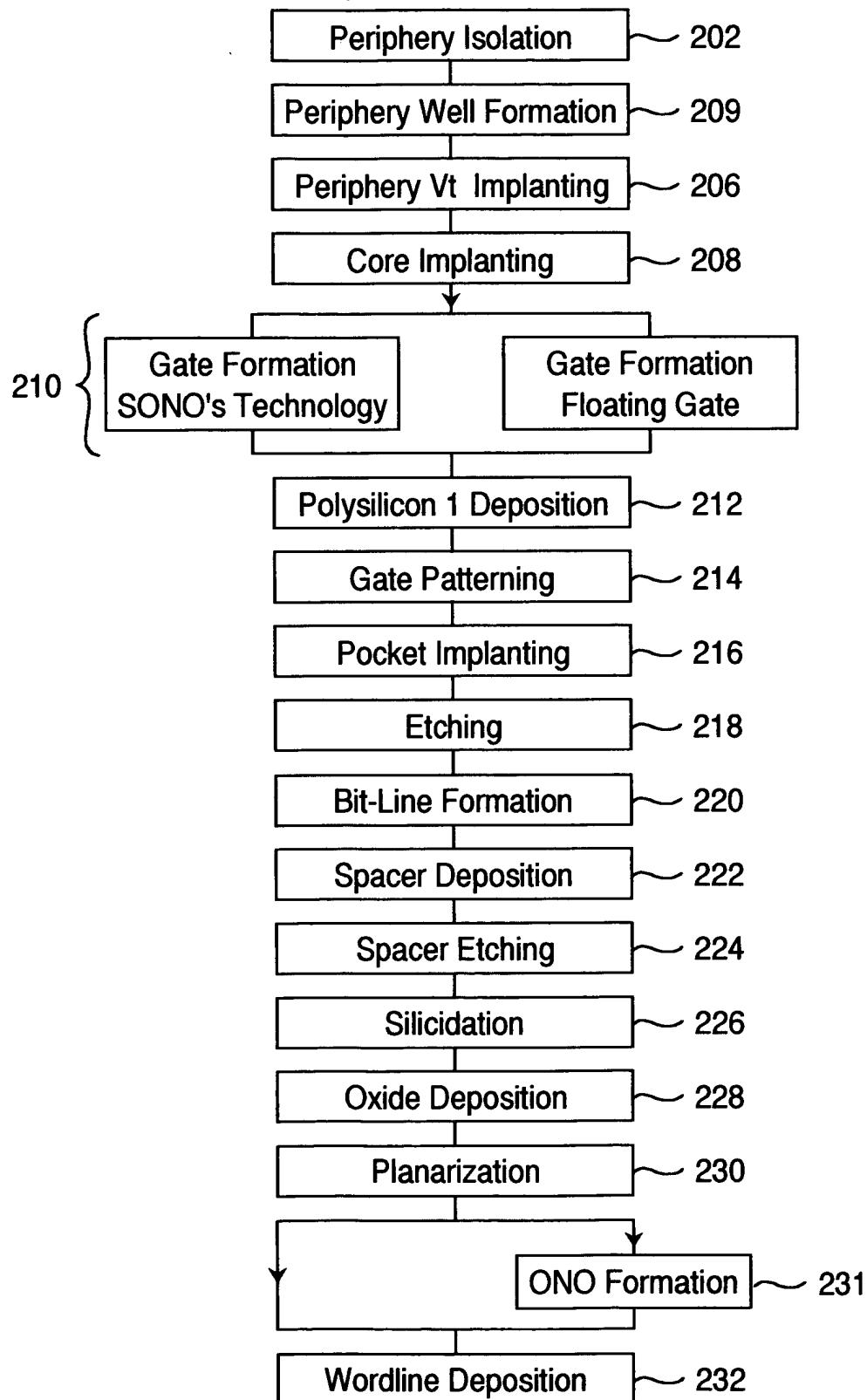


FIG. 2

Replacement Sheet

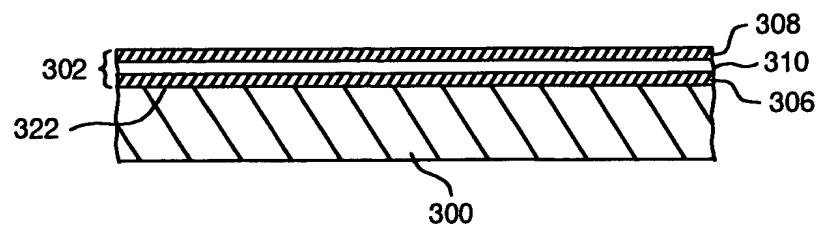


FIG. 3

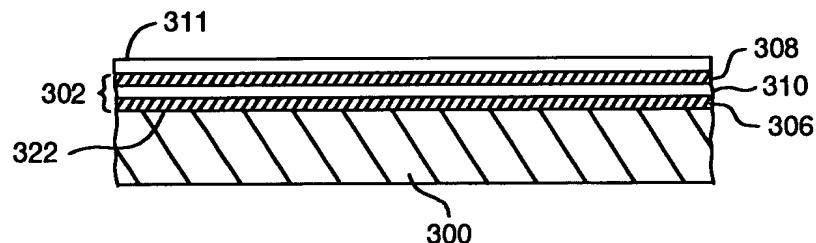


FIG. 4

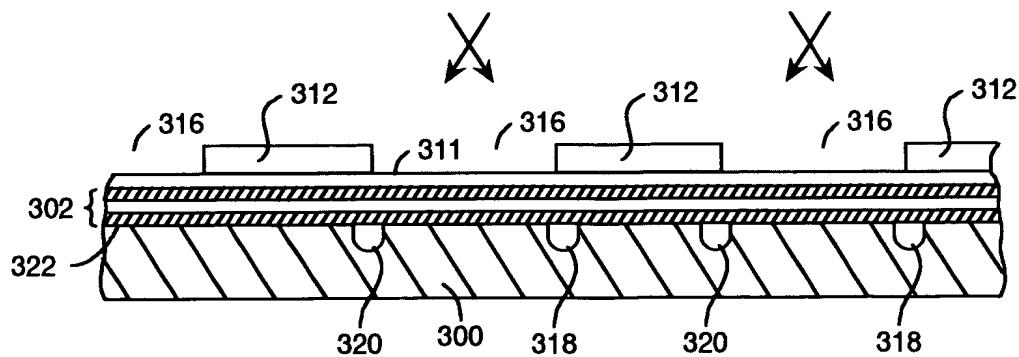


FIG. 5

Replacement Sheet

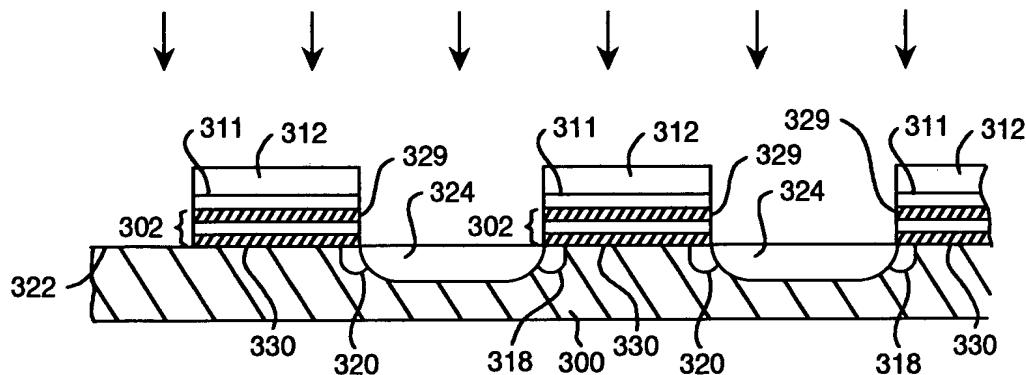


FIG. 6

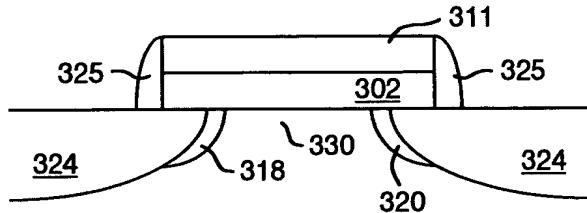


FIG. 7

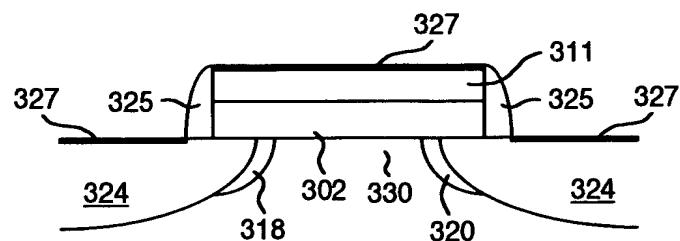


FIG. 8

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Replacement Sheet

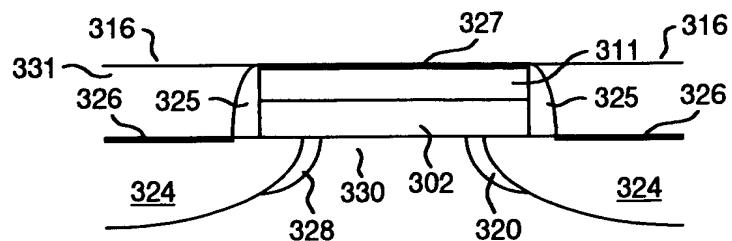


FIG. 9

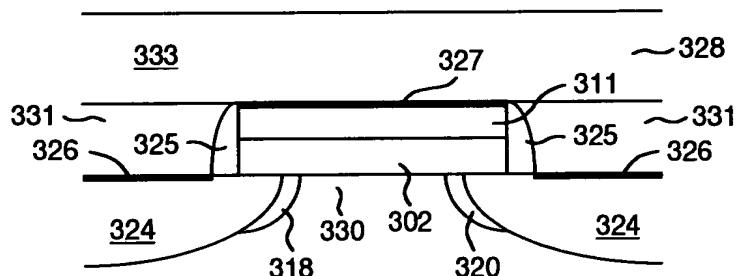


FIG. 10

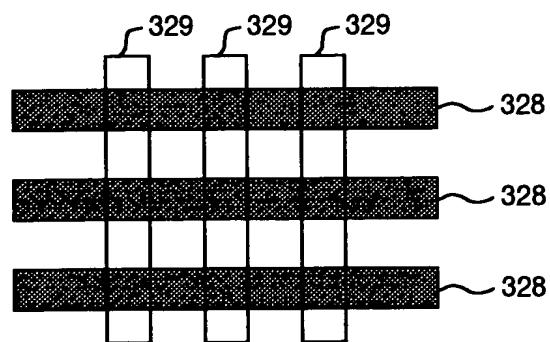


FIG. 11